

INCHANGE SEMICONDUCTOR

G(1)

123

isc N-Channel MOSFET Transistor

2N0609

D(2)

S(3)

2, Drain

3. Source

pin 1, Gate

• FEATURES

Static drain-source on-resistance:

R⊳s(on)≤9.1mΩ

- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

- Ultra Low On-resistance
- Fast Switching

• ABSO	LUTE MAXIMUM RATINGS(Ta=25°C	TO-220C package		
SYMBOL	PARAMETER	VALUE	UNIT	↓ -B-F + S
V _{DSS}	Drain-Source Voltage	55	V	
V _{GS}	Gate-Source Voltage	±20	V	
l _D	Drain Current-Continuous	100	A	
PD	Total Dissipation @T _c =25℃	190	W	
Tj	Max. Operating Junction Temperature	175	°C	MIN MAX
T _{stg}	Storage Temperature	-55~175	°C	A 15.50 15.90 B 9.80 10.20 C 4.20 4.50 D 0.70 0.90
• THERM		F 3.40 3.70 G 4.98 5.18 H 2.68 2.90		
SYMBOL	PARAMETER	МАХ	UNIT	J 0.44 0.60 K 12.80 13.40 L 1.20 1.45
Rth(j-c)	Channel-to-case thermal resistance	0.79	°C /W	Q 2.70 2.90 R 2.30 2.70 S 1.29 1.35 U 6.45 6.65
				V 8.66 8.86

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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =250 μ A	55			V
V _{GS} (th)	Gate Threshold Voltage	VDS=VGS; I _D =250 µ A	2.0		4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =55A			9.1	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =55V; V _{GS} = 0V			25	μA
V _{SD}	Diode forward voltage	I _S =55A, V _{GS} = 0V			1.3	V

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